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Supplementary Information

Efficient polymer solar cells based on a cathode interlayer of dicyanomethylenated indacenodithiophene derivative with large π -conjugated and electron-deficient properties

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1. Synthesis and characterizations



Scheme S1. Synthesis procedures of TBIDTD and TBIDTCN. i. K_2CO_3 , Pd(PPh₃)₄, toluene, reflux, 16 h; ii. malononitrile TiCl₄, pyridine, CHCl₃, reflux, 24 h; iii. Trimethylamine, THF, 48 h; iv. Trimethylamine, THF, 48 h.



Scheme S2. Synthesis of PBE-THBBr. i. 1,6-Dibromohexane, K₂CO₃, DMF, r.t., 38 h;
ii. n-BuLi, THF, -78 ℃, 12h.

I-THBBr: 5-Iodo-1,2,3-trihydroxybenzene (I-THB) (3.78 g, 15 mmol) was dissolved in N,N-Dimethylformamide (DMF) (80 mL), and the solution was degassed with nitrogen for 15 min. Then 1,6-Dibromohexane (18.3 g, 75 mmol) and K₂CO₃ (20.7 g, 150 mmol) were added to the system. The reaction mixture was stirred at room temperature for 38 hours, after that, water was added to quench the reaction and the mixture was extracted with ethyl acetate, then the organic phase was washed with water and dried over anhydrous Na₂SO₄. The solvent was evaporated and the residue was purified with flash column chromatography (CH₂Cl₂/hexane 1: 2) to get the product as white solid (8.45 g, 76%). ¹H NMR (500 MHz, CDCl₃) δ 6.87 (s, 2H), 4.00-3.90 (m, 6H), 3.4-3.42 (m, 6H), 1.97-1.87 (m, 6H), 1.87-1.80 (m, 4H), 1.79-1.72 (m, 2H), 1.59-1.48 (br, 12H). GC-MS (m/z): [M]⁺ calculated for C₂₄H₃₈Br₃IO₃: 741.2. Found: 741. Anal. Calcd for C₂₄H₃₈Br₃IO₃: C, 38.89; H, 5.17. Found: C, 38.92; H, 5.28.

PBE-THBBr: A solution of I-THBBr (7.41 g, 10 mmol) in dry THF (80 mL) was stirred under N₂ at -78 °C. After 10 min, a solution of n-BuLi (4.6 mL, 11 mmol) in hexane was added dropwise. The mixture kept on stirring for 90 min at -78 °C, then the formed organolithium derivative was quenched by isopropoxyboronic acid pinacol ester (2.23 g, 12 mmol). The reaction mixture was stirred at room temperature for another 12 hours, subsequently. Then an

excess aqueous solution of ammonium chloride was added to the system to quench the reaction and the mixture was extracted with Et_2O . The organic layer was washed with brine and dried over anhydrous Na_2SO_4 . The solvent was evaporated and the residue was purified with flash column chromatography (CH₂Cl₂/hexane 3:1) to get the product as white solid (5.26 g, 71%). ¹H NMR (300 MHz, CDCl₃) δ 6.99 (s, 2H), 4.10-3.92 (m, 6H), 3.42 (t, J = 6.8 Hz, 6H), 1.96-1.68 (br, 12H), 1.60-1.43 (br, 12H), 1.33 (s, 12H). GC-MS (m/z): [M]⁺ calculated for C₃₀H₅₀BBr₃O₅: 741.3. Found: 741. Anal. Calcd for C₃₀H₅₀BBr₃O₅: C, 48.61; H, 6.80. Found: C, 48.95; H, 6.45.

2. Supplementary Figures



Fig. S1. TGA curves of TBIDTD and TBIDTCN.



Fig S2. (a) Cyclic voltammograms of CILs at room temperature, 0.1 M TBAPF6 in CH₃CN solution; (b) EPR spectra of the CILs in the solid state.



Fig. S3. Current density-voltage (J-V) curves of the PTB7:PC₇₁BM based devices with different thicknesses of (a) TBIDTD and (b) TBIDTCN under the 100 mW cm⁻² AM 1.5G irradiation.



Fig. S4. (a) I–V curves of the conductivity measurements of TBIDTD and TBIDTCN with (b) a configuration of ITO/TBIDTD (TBIDTCN)/Al.

3. Supplementary Tables

CIL	Thickness (mg ml ⁻¹)	Thickness (nm)	J _{sc} (mA cm⁻²)	V _{oc} (V)	FF (%)	PCE _{max} (%)
TBIDTD	0.3	2	16.14	0.763	66.2	8.15
	0.5	3	16.23	0.766	69.3	8.62
	1	8	15.69	0.758	31.2	3.71
TBIDTCN	0.3	2	16.35	0.762	68.9	8.60
	0.5	3	16.57	0.768	72.2	9.19
	1	7	16.03	0.755	65.2	7.89
	1.5	12	15.75	0.755	35.2	4.18

Table S1. Device parameters of the PTB7:PC₇₁BM based PSCs with different

thicknesses of TBIDTD and TBIDTCN.

Table S2 Conductivity results, the conductivities were calculated from Ohm's law at the linear regions.

CIL	Thickness (nm)	Conductivity (S m ⁻¹)
TBIDTD	30	2.29×10 ⁻⁵
TBIDTCN	30	6.13×10 ⁻⁵